



Center for Night Vision and Electro-Optics

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HP-41CX PROGRAMS FOR HgCdTe DETECTORS AND IR SYSTEMS

by DAVID R. KAPLAN

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CONTENTS

I	INTRODUCTION	1
II	PROGRAM DOCUMENTATION	5
	1. FLAG	5
	2. NEdT, DET RNG	6
	3. D*, QBB	9
	4. BB	12
	5. SV	16
	6. GR-DIFF	18
	7. HCT, X, EG	21
	8. NI-RØA	23
	9. CONSTNT	26
	10. INJEFF	28
II	FINAL COMMENTS	31



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HP-41CX PROGRAMS FOR HgCdTe DETECTORS AND IR SYSTEMS

I. INTRODUCTION

Programs have been written for the HP-41CX which aid in the analysis of HgCdTe detectors, focal planes, and infrared systems. They have been installed as a "bundle" in an HP-41CX and a "WALL" (write-all) operation has been performed, saving the group of programs and machine status to magnetic cards. They have been written to run in a basic HP-41CV or HP-41CX with no card reader or additional ROMs required. An HP-41C with less than maximum RAM will be unable to read this WALL configuration and will be unable to hold all the programs in memory at the same time, but a subset can be loaded by hand from the enclosed listings.

The purpose of this report is to describe the status of the HP-41CX after the WALL cards have been read, and to provide the user with information needed to use the programs.

It is assumed that the user has some familiarity with the operation and programming of the HP-41 family of pocket calculators. However, the description will begin with a brief review of the more pertinent characteristics and procedures.

The HP-41CX can have many different unique programs in memory at the same time. Jumps to perform a subroutine or to alter program flow are referred to labels (LBLs) which identify the target location. There are a limited number of short (quick) labels available, and when writing a program, it's important to keep track of label usage. The HP-41CX provides the capability, when desired, of separating programs with an END statement. The short labels cannot be reached by GTO (go to, jump) or XEQ (execute, gosub) commands beyond an END statement. This means that such labels are local labels and don't conflict with identical labels in other programs separated by an END statement. There are, however, global labels available which permit the user to go directly to a program from anywhere in RAM. These also permit one program to GTO or XEQ another program, even though they are separated by an END statement. Performing a CATALOG 1 causes the HP-41CX to list the global labels. The listing may be paused with the R/S key, and you may step forward or backward through the listing with the SST and BST keys. You may put yourself in a desired program by listing CATALOG 1, pausing with the desired program in the display, and pressing the \leftarrow key.

The global labels of the programs included in this WALL configuration are listed on the next page. Global labels need not necessarily be separated by END statements, and some of the labels in this group of programs, in fact, are not. Indented programs are included in the same local area with program above.

LABEL	DESCRIPTION
FLAG	Puts calculator flags back to a default status.
NEdt	Noise equivalent delta temperature of an IR system, and photons collected in an integration time.
DET RNG	Estimates detection range of a target.
D*	D-Star (PV, Johnson, and BLIP), RoA BLIP, D*lambda to D*BB conversion factor.
QBB	Blackbody photon flux.
BB	General purpose blackbody calculations.
SV	General purpose root finder used by other programs.
GR-DIFF	RoA, temperature, cutoff interpolator/extrapolator.
HCT	X of Hg(x)Cd(1-x)Te from cutoff and temperature.
EG	Bandgap from x and temperature.
NI	Intrinsic carrier concentration from material parameters.
RØA	RoA product from material parameters.
CONSTNT	Useful physical constants.
INJEFF	Direct Injection injection efficiency.

The following USER key definitions are also included. (In USER mode, the following keys perform the indicated operation.)

PRESSING	WILL RESULT IN
TAN	PACK
SHIFT TAN	CLRG (clear all data registers)
SHIFT R/S	Run the FLAG program

Twenty-six registers have been reserved for data storage (registers 00 through 25.) Thirty-five registers of the 319 available in an empty machine are unused and available for either additional programming or additional data storage. Each register has room for approximately five program steps. Should more room be needed for a different, lengthy program, and if you are using an HP-41CX or an HP-41C(V) with an extended memory module, you may SAVEP any program in RAM to EXTENDED MEMORY (which is similar to a RAM-DISK) and then clear the program from RAM. This may be repeated as necessary with other programs until EXTENDED MEMORY is full. Programs in EXTENDED MEMORY cannot be run, but you may GETP them back into RAM, if there is enough RAM available.

Of the 26 data registers available, only the first 15 STO (store) and RCL (recall) statements are quick access (one-byte statements instead of two-byte statements.) You can ignore this fact, but it is the reason that the first 15 registers are used most often. Since there are more than 15 different physical parameters involved in the above programs and some data registers are needed for bookkeeping or temporary scratch storage, there is not a firm relationship from global program to global program between any physical parameter and any data register. You can rest assured that the right data are in the right place at the right time when running a given program. BUT don't assume that data entered while running one program will be correctly placed, should you go to another global program which requires the same data. It is advisable to perform a CLRG (SHIFT-TAN in USER mode) and reenter all necessary data when moving to a new program.

There is a similar caution concerning the HP-41CX flags. There are 56 flags which are used by the HP-41CX, 30 of which are user alterable. The status of the first five are indicated on the LCD display. Since the calculator is slow (as computers go), some calculations are done once, the data are stored, and a flag is set to let the program know that the calculation need not be done again, unless certain parameters are altered. If these parameters are altered, the flag is automatically cleared so that a new calculation will be performed when required. Flags are used to control program flow for other reasons as well. To keep the user informed, only the first five flags (which are visible in the display) are used in this fashion. Different global programs may use the same flag to mean different things, so it is advisable when moving to a new global program (or just starting a program) to check to see that the five displayed flags (0 through 4) are clear. If you can't see them, they're clear. Running the FLAG program (SHIFT-R/S in USER mode) will insure that all flags are clear. This will leave you in the FLAG program, and then you will have to go to the program you wish to run.

Running a program generally proceeds as follows. With the exception of FLAG which may be run at any time by pressing SHIFT R/S, the user must, first, position himself within the program of interest. This may be done, as described above, by using CATALOG 1 and pressing R/S to stop the catalog scan with the desired program name in the display, or by going directly to the program of interest with the GTO command. For example, to run the blackbody program (BB), press keys as follows: SHIFT GTO ALPHA BB ALPHA.

Make sure that flags 0 through 4 are clear. It may be wise to do a CLRG to increase the likelihood that, should you fail to provide all the necessary data to the program, an error will occur or invalid results will be clearly invalid.

The programs generally require data to be input before any results may be computed. The top row of keys (A, B, C, D, E) and their SHIFTed counterparts (a, b, c, d, e) are used to communicate with a program. This is because, WHEN IN USER MODE, pressing one of these keys will begin program execution at the label (LBL) which matches the key. These labels are local. If no such label exists in the current program area, then the function identified on the keyboard is executed instead. For example, suppose the current program area contains the instruction sequence:

: LBL d 5 * 1 + RTN :

With USER mode active, pressing SHIFT D will cause the program to being running at LBL d, where it will multiply the contents of the X register (the display) by 5, then add 1 and, finally, stop showing the answer again in the X register.

The programs are written so that pressing certain keys will cause data which have been entered into the X (or X and Y) (or X, Y, and Z) register to be stored away for later use. Pressing certain keys (perhaps after some additional data entry) will cause desired calculations to be performed and the results displayed. Which keys do what varies from program to program, and the functions are not indicated on the keyboard. You must, therefore, either remember the key definitions or refer to a document such as this report. It is common, when an individual, dedicated program is stored to a magnetic card, to write the definitions for each key on that magnetic card. The card is conceptually divided into five parts horizontally representing the five keys in the top row, and two parts vertically representing the unshifted and shifted labels. The upper half represents the shifted keys. Although this has not been done with the WALL cards, the same convention will be followed by including in each program description a drawing based on this layout which defines the operation of each key.

It is somewhat inconvenient to use a single key to enter multiple data, but it is necessary, since there is often more data required for a calculation than there are keys. Referring to one of these drawings, ENTER means press the enter key on the keyboard after keying in the requested data. This pushes the data just entered up into the Y register and permits the user to enter additional data in the X register. Another ENTER pushes the contents of Y into Z, X into Y, so additional data may be placed in X. After keying in all the requested data for a key, press that key so that the program will store it. Continue from key to key, entering in all data required to compute the parameter desired. Note that some programs calculate more than one parameter and that some parameters may not require that all the data indicated on the drawing be input. Which parameters require which data comes from experience or referral to this report.

Once all the necessary data have been keyed and stored, pressing the FIND key for the desired parameter will initiate the calculation to produce the answer for that parameter. Obviously, pressing FIND before all the necessary support data have been entered will, very likely, produce invalid results. It may even produce an operational error; e.g., divide by zero, causing the calculation to terminate. Under

most circumstances no harm is done when this occurs. However, NOTE that some programs call other programs. If the error occurs in the called program, you will be left in that program, not in the program from which you started. It is advisable, should such an improper termination occur, to re-position yourself via CATALOG 1 or GTO to the program of interest. It is probably, also, wise to clear any set flags.

If incorrect data have been keyed and stored, it may be corrected by performing the correct data entry sequence for the key dedicated to that data. This means that you will have to reenter all the data associated with that key. This is also true if you wish to change any data, either before or after FINDing a result. To recalculate a result with different initial conditions, you need only reenter the data associated with the key whose data you wish to alter. Then, press the appropriate FIND key for the result desired.

What follows is user documentation and description for each of the programs.

II. PROGRAM DOCUMENTATION

1. FLAG. This is a very short program designed specifically to restore all 55 flags of the HP-41CX to default status. It clears flags 0 through 25, sets the display to FIX 2 format, sets DEG mode, calls for a period as the decimal point, and calls for commas between digit groupings of three. It alters no data registers. This program may be quickly run by pressing SHIFT R/S in the USER mode if FLAG has been assigned to this key.

The FLAG program on the WALL cards contains undocumented program steps and should not be altered or single-stepped in RUN mode.

Also, included is a listing for FLAG which simulates the short version and which contains no undocumented operations. This version is significantly slower than the short version, but it may be keyed by hand and needs no precautions.

PROGRAM LISTINGS FOR FLAG

Two listings are given. The first is very fast and short but contains undocumented code which can only be created by procedures unavailable to most users. It is included on the WALL cards. The second is longer and significantly slower but may be easily keyed by hand.

01/10/1986

01+LBL "FLAG" 02 "<\\bar{x}+" 03 ASTO d 04 CF 03 05 .END.

01+LBL "FLAG"
02 .025
03+LBL 00
04 CF IND X
05 ISG X
06 GTO 00
07 SF 26
08 SF 27
09 SF 28
10 SF 29
11 FIX 2
12 DEG
13 RTH
14 END

2. NEdT, DET RNG.

Lambda Initial ENTER Lambda Final (µM)	./# cold shld ENTER F/# signal	Bkgnd temp ENTER Detector temp (Kelvin)	Integ. time (sec) ENTER Quant. eff. (percent)	Detector area (sq. cm.)
SHIFT A	SHIFT B	SHIFT C	SHIFT D	SHIFT E
FIND	FIND Photons per	Target dT (K) ENTER	S/N criteria ENTER	RoA (ohm-cm ²)
NEdT	integration	Target Area	Atm transmissn	(0 0 2)
(K)	time.	(sq. m) ENTER	(percent/km) FIND	
		Focal length	Detection Rng	
. я _	_ B	(mm)	(km) n	. Ε

Below is a table showing the data required, registers used, sample test data, and results.

	REQ'D FOR NEdT	REQ'D FOR PHOTONS	_	REGISTER USED	TEST DATA
LAMBDA INITIAL	х	х	х	1	3
LAMBDA FINAL	X	X	X	10	5
F/# COLD SHIELD	X		X	17*	1
F/# SIGNAL	X	X	X	4	1.4
BACKGROUND TEMPERATURE	X	X	X	3	300
DETECTOR TEMPERATURE	X		X	14	200
INTEGRATION TIME	X	X	X	5	4E-5
QUANTUM EFFICIENCY	X	X	X	18	60
DETECTOR AREA	X	X	X	2	1E-5
RoA	X		X	15	50
TARGET DELTA TEMP			X	16	3
TARGET AREA			X	11	3
SYSTEM FOCAL LENGTH			X	12	100
S/N CRITERIA			X	13**	10
ATM. TRANSMISSION (PERCENT/KM)			X	20***	70.71

RESULTING NEdT = 0.15511 K

Other registeres used:

RESULTING SIGNAL PHOTONS = 4.02 E5

0,6,7,8,9

RESULTING DETECTION RANGE = 3.885 km

^{*} This register actually contains the ratio of the f/numbers squared.

^{••} This register used for scratch as well, so S/N not saved.

^{***} SQR (transmission percent/100) actually stored.

This program finds (1) Noise equivalent delta temperature (NEdT), (2) number of photons collected by a detector (or an equivalent detector, for TDI) through the system in an integration time, and (3) detection range for a target.

The NEdT for an IR system is calculated from certain system and detector parameters. It is a relatively abbreviated calculation, so the results are only approximate. Assumptions made include that the noise comes only from the detector or the background, that the noise bandwidth is the reciprocal of the integration time, that the quantum efficiency is constant with respect to wavelength, and that the detector noise is due to shot noise at zero bias.

The calculation performed is:

NEdT =
$$SQR(2*PC + (4kTt/Ro/e^2))$$
,

where Q.E. is the detector quantum efficiency;

t = detector integration time;

T = detector temperature;

Ro = detector zero bias dynamic resistance;

A = detector active area; and

PC is the charge absorbed by the detector/t due to photons.

or,
$$PC = \frac{Q A (Q.E.) t}{(2 * (cold shield F/#))^2}$$

where $Q = \text{photon flux rate from cuton to cutoff/cm}^2/s$, and

SC is the signal charge absorbed by the detector/t per degree change in scene temperature.

or,
$$SC = \frac{dQ}{dT} \frac{A (Q.E.) t}{(2 * (signal F/#))^2},$$

where $\frac{dQ}{dT}$ = change in signal flux per change in scene temp.

The photons per integration time, found by pressing key B, is the number of SIGNAL photons collected through the optics of the indicated system (using the signal F/#) which produces signal carriers. For TDI systems the integration time entered should be the integration time per detector times the number of detectors in TDI, so that the number of carriers accumulated is the number for the TDI column. To find the number of background carriers collected, set the signal F/# equal to the background F/#.

The detection range is calculated by finding the range at which the image of the target is sufficiently smaller than the detector, so that the S/N is as desired. The signal is attenuated, based upon the entered atmospheric transmission per kilometer. The SV (solve) program is called to perform the iteration to a solution.

$$S/N = (transmission)^{\circ}(range) \times (target delta T) \times (target area) \times f^{2}$$

$$NEdT \qquad A \qquad RangeA2$$

PROGRAM LISTING FOR NEdT, DET RNG

01/10/1986	51 201 17	194 X†2	157 Xt2
	51 RCL 13 52 *	105 STO 17	158 /
	53 RCL 97	196 RTN	159 +
01+LBL -BET RNG-	54 -	107+LBL c	
02+LBL C	55 RTN	108 STO 14	
03 STO 12	JU KIN SCALDI «NEJY»	100 310 14	
84 RDN	57+LBL A	109 X<>Y	162 *
65 STO 11	58 .5	110 STO 03	163-6
06 RDN	59 ST+ 03	111 RTN	164 +
97 STO 16	60 SF 00	112+LBL d	165 RCL 08
08 RTN	61 XEQ 08	113 STO 18	166 *
09+LBL D	62 STO 96		167 2
10 100	63 1	115 STO 95	168 +
	64 ST- 03	116 RTN	169 27
11 / 12 SQRT			170 /
13 STO 20	65 XEQ 08	_	
14 X<>Y	66 CF 30	119 RTN	172 Xt2
15 STO 13	67 .5	120+LBL E	173 /
16 XEG -MEGT-	63 ST+ 03	121 STO 15	174 RCL 97
17 RCL 13	69 RDN	122 RTN	175 /
18 *	79 RCL 06	123+LBL B 124 CF 00	176 +
	71 X<>Y	124 CF 88	177 RCL 03
28 X<>Y	72 ST- 06	125+LBL 98	178 X12
	73 +	126 SF 91	179 *
22 X>Y?	74 RCL 17		188 RCL 03
	75 /	123 XEQ 01	
24 /	76 215 E13	129 STO 00	
25 RCL 12	77 RCL 14		
26 X†2	78 *	131+LBL 01	
27 RCL 11	79 RCL 15	132 14388	185 *
28 *	88 /	133 X()Y	186 RCL 04
29 RCL 02	81 RCL 02	134 /	187 X 1 2
39 /	82 *	135 RCL 03	188 /
31 *	83 RCL 05		
32 SQRT	84 * 85 +	137 STO 08	170 F
33 1 E4	86 SQRT	100 E	191 RCL 05 192 *
34 /		140 RCL 08	
35 STO 13	88 /	140 KCL 08	193 FS?C 01 194 RTN
36 SF 10	89 FIX 5	142 2	195 RCL 80
37 •R•	90 "NEdT="	143 +	196 -
38 ASTO 96	91 ARCL X	144 RCL 98	197 FS? 88
39 0	92 AVIEN	145 EtX	198 RTN
40 X<>Y	93 RTN	146 STO 07	199 SCI_2
41 FIX 3	94+LBL a	147 /	200 CLA
42 XEQ "SV"	95 STO 10	148 RCL 08	201 ARCL X
43 CLR	96 X<>Y	149 X†2	202 TH PHOT
44 ARCL X	97 STO 01	150 RCL 93	203 AVIEW
45 "HKM"	98 RTN	151 +	204 RTN
46 PROMPT	99+LBL b	152 .5	205 END
47+LBL "R"	180 X(Y?	153 +	COO CITE
48 RCL 29	101 GTO 99	154 2	
49 X<>Y	102 STO 04	155 /	
50 YtX	193 /	156 RCL 07	
- - - · · ·	103 /	וסט אטב פון	

3. D*, QBB.

				<u> </u>
Lambda Initial ENTER Lambda Final (µM)	Quant. Eff. (percent) ENTER Field of View (full angle) (degrees)	Bkgnd temp ENTER Detector temp (Kelvin)	RoA (ohm-cm ² 2)	FIND RoA BLIP
SHIFT R	SHIFT B	SHIFT C	SHIFT D	SHIFT E
FIND	FIND	FIND	source temp FIND	FIND photon flux
D* (PV)	D* (BLIP)	D* (JOHNSON)	D*lambda to D*BB conversion factor	with Q.E. and FOV
_ A _	В	_ с _	ם ם	Ε _

Below is a table showing the data required, registers used, sample test data, and results.

	REQ'D FOR D*PV	FOR	REQ'D FOR D*JHNSN	REQ'D FOR C.F.	FOR	FOR		TEST DATA
LAMBDA INITIAL	x	X		X	Х	X	5	8
LAMBDA FINAL	X	X		X	X	X	10	11
QUANTUM EFFICIENCY	X	X			X	X	11	50
FIELD OF VIEW	X	X			X	X	13	120
BACKGROUND TEMP.	X	X				X	12	300
DETECTOR TEMPERATURE	X		X			X	14	80
RoA	X		X				9	0.1
SOURCE TEMPERATURE				X			12*	500
RESULTING D*PV		= 1.93 E	E10		OTF	HER REG	GISTERS	USED:
RESULTING D*BLIP		= 4.82 E	E10		0,6,7	7,8,15		
RESULTING D*JOHNSON		= 2.11 E	E10					
RESULTING CONVERSION F	ACTOR	= 5.60						
RESULTING PHOTON FLUX		$\approx 1.65 E$	E17/CM ^ 2/S	EC				
RESULTING ROA BLIP		= 0.522						

^{*}Source temperature is placed temporarily in register 12; background temperature is restored to register 12, at the end of the calculation.

This program contains routines to find six different parameters associated with photovoltaic detector D-star.

(1) D*JOHNSON is the detectivity based on the assumption that the detector shot noise at zero bias is the only noise source. It is computed from:

$$D^*JOHNSON = e \underbrace{(Q.E.) (cutoff) SQR(Ro^*A/(4kT))}_{hc}.$$

(2) D*BLIP is the detectivity based on the assumption that the background noise is the only noise source. It is computed from:

$$D*BLIP = \frac{\text{(cutoff) SQR((Q.E.)/(photon flux))}}{\text{SQR(2) h c SIN(FOV/2)}}.$$

(3) D*PV is the detectivity which includes both detector and background noise sources and is computed from the above as:

$$D^*PV = \frac{(D^*JOHNSON) (D^*BLIP)}{SQR((D^*JOHNSON)^2 + (D^*BLIP)^2)}.$$

(4) Blackbody photon flux is the photon collection rate per second per square centimeter of detector area for the given quantum efficiency and field of view. It is found by twice calling a routine which calculates the flux from lambda = 0 up to lambda. Lambda is first set to cutoff, then to cuton, and the results are subtracted. The basic routine which is called is:

$$Q = a \frac{SUM(X^2 + 2*X/n + 2/n^2)}{n EXP (nX)}, \qquad \text{for } n = 1,2,3 \text{ and } X = lambda, \text{ and}$$

where $a = 2 PI c (kT/(hc))^3$.

(5) The conversion factor is the factor which converts a blackbody D* to a lambda peak D*. It is a theoretical value which, here, assumes that the quantum efficiency of the detector is constant between cuton and cutoff. For this calculation, it is assumed that the peak response is at the cutoff. It is calculated from (where sigma is the Stefan-Boltzmann constant):

C.F. = (photon flux)
$$(b/a)$$
, where a is as above, and

$$b = \frac{2 PI k^3}{c \text{ (sigma) (source temperature) h }^2 \text{ (lambda cutoff)}}.$$

(6) RoA BLIP is the value of the RoA for which D*JOHNSON and D*BLIP equal one another. It is, therefore, the RoA for which the D*PV is .7071 of D*BLIP. Requesting this calculation presents the answer in the display and, also, stores this value in register 9. This means that further calculations for D* will be based on this RoA.

PROGRAM LISTING FOR D*, QBB

01/10/1986		
01, 10, 1,00	49 XEQ 88	101+LBL 00
	49 XEQ 08 50 RCL 06	192 2
	51 -	193 RCL 97
01+LBL e	52 FS? 02	184 /
	5.3 RTN	105 RCL 08
02 1 07 CTN 00	54 RCL 13	196 +
03 310 07 04 VEN D	55 2	197 RCL 98
OF VER D	56 /	108 *
OJ AER C	57 SIN	109 2
00 / 07 V42	55 2 56 / 57 SIN 58 X†2 59 * 60 RCL 11	110 RCL 07
OOADIA	59 +	111 Xt2
OOVEDE U	60 RCL 11	112 /
10 07 31U 07	61 %	113 +
10 KIN 11ALDI S	62 STO 15	114 RCL 87
13 CE 88	63 SF 00	115 /
12 Ur. 00 17 CTO 10	64 RTN	116 RCL 08
13 310 10	65+LBL B	117 RCL 07
17 A\/! 15 CTO 05	66 XEG E	118 *
13 310 BJ	67 SQRT	119 EtX
IO KIN	68 RCL 11	128 /
14 AFDF 0	69 X<>Y	121 +
10 UF 00	78 /	122 DSE 97
12 210 12	61 % 62 STO 15 63 SF 00 64 RTN 65+LBL B 66 XEQ E 67 SQRT 68 RCL 11 69 X<>Y 70 / 71 RCL 10 72 *	123 GTO 00
20 A\/I	72 *	124 FS? 02
21 310 11	72 * 73 356 E14	125 RTN
02 1 03 STO 09 04 XEQ B 05 XEQ C 06 / 07 X***2 08**LBL d 09 STO 09 10 RTH 11**LBL a 12 CF. 00 13 STO 10 14 X<>Y 15 STO 05 16 RTH 17**LBL b 18 CF 00 19 STO 13 20 X<>Y 21 STO 11 22 RTH 23**LBL c 24 CF 00 25 STO 14 26 X<>Y 27 STO 12 28 PTH	74 * 75 RTN 76+LBL C 77 SCI 2	126 RCL 12
237LDL	75 RTN	127 X†2
29 UP 00	76+LBL C	128 RCL 12
20 210 14	77 SCI 2	129 *
25 AS71	78 RCL 09	130 6324 E7
21 210 12	79 RCL 14	131 *
28 RTN 29+LBL "B*" 38+LBL R 31 XEQ 8 32 XEQ C 33 R-P	89 /	132 *
277LDL "9+"	81 SQRT 82 RCL 10	133 RTN
307LDL H	82 RCL 10	134+LBL D
31 YER 0	83 *	135 X() 12
32 AEW 6	84 RCL 11	136 STO 99
33 KT 74 CTO 90	85 *	137 CF 66
34 STO 08	86 10854 E5	138 SF 02
35 P-R	87 *	139 XEQ E
36 * 37 RCL 08	88 RTN	140 CF 02
38 /	89+LBL "QBB"	141 2216
39 RTN	90+LBL 08	142 *
40+LBL E	91 3	143 RCL 10
41 SCI 2	92 STO 97	144 /
42 RCL 15	93 CLX	145 RCL 12
43 FS? 00	94 14388	146 /
43 F3? 00 44 RTN	95 X<>Y	147 RCL 80
45 RCL 05	96 /	148 STO 12
46 XEQ 08	97 RCL 12	149 RDN
47 STO 06	98 /	15 0 1/X
	99 STO 08	151 EHD
48 RCL 18	100 CLX	- ****

4. BB.

INITIALIZE	FIND or ENTER Blackbody Temp. (K)	FIND or ENTER Cutoff (µM)	COMPARE Lambda Max versus BB Temp. (maximized photon flux)	COMPARE Lambda Max versus BB Temp. (maximized power)
SHIFT A	SHIFT B	SHIFT C	SHIFT D	SHIFT E
PREFIX	PREFIX	PREFIX	FIND	FIND
<u>d</u> dT	integral to infinity wrt lambda	integral to cutoff	Photon Flux	Power Flux
	СН	OICE		
A	В	С	D	E

Below is a table showing sample test data and results.

LAMBDA FINAL = $5 \mu M$ (not required for integral to infinity) BLACKBODY TEMP. = 300K REGISTERS USED: 0 THRU 15

RESULTS

PREFIXES PRESSED	Q (photons)	W (watts)
NONE	2.058 E16 /cm²/s/μM	8.175 E-4 /cm²/μM
INTEGRAL TO INFINITY (ITI)	4.105 E18 /cm²/s	4.592 E-2 /cm²
INTEGRAL TO CUTOFF (ITC)	1.320 E16 /cm²/s	5.901 E-4 /cm²
DERIVATIVE WRT TEMP (DWT)	6.580 E14 /cm²/s/μM/K	2.614 E-5 /cm²/μM/K
DWT, ITI	4.105 E16 /cm²/s/K	6.123 E-4 /cm²/K
DWT, ITC	4.749 E14 /cm²/s/K	2.149 E-5 /cm²/K

The COMPARE functions permit you to key in either wavelength or temperature and calculate the other (temperature or wavelength) for maximum flux. For example, keying in 300 and pressing SHIFT D will produce the value 12.23. This means that for a 300 K blackbody, the wavelength of peak photon flux

density is 12.23 μ M. Or conversely, a blackbody whose peak photon flux density is at 300 μ M wavelength has a temperature of 12.23 K. The operation for SHIFT E is the same, except the criterion is the wavelength for peak power density. Keying 300 and SHIFT E produces the value 9.659. NOTE: The data entered prior to a COMPARE operation does not alter any values that have been stored for wavelength or temperature via SHIFT B or SHIFT C.

This program uses the keys a little differently. First, before doing anything else, you must initialize the program by pressing SHIFT A. This configures the HP41 data registers and flags for the rest of the program. It also is used to clear partial entries, as described below.

Second, at most only two initial conditions are required, wavelength and temperature, and the keys which are used to store these conditions may also be use to recall (or verify) them. The HP41 has a flag which it uses to keep track of whether a numeric key (0 through 9) has been pressed. This flag is not visible in the display. As soon as any numeric key is pressed, this flag gets set. The program uses this fact to determine if the user is storing data or requesting an answer. If the flag is set, the user is assumed to be storing data, and the value in the display is stored as the new value of the variable designated by the key pressed. If the flag is clear, the present value of the requested variable is displayed. The program clears this flag automatically after every operation, so the presence (or absence) of new numeric key presses may be sensed. NOTE: If this flag is set and any of the unshifted keys are pressed, the program updates the wavelength with the current value in the X register (the display), in addition to performing the desired operation. If you have done some simple keyboard calculations (thereby setting the flag), and you now wish to perform a program operation without altering the value for wavelength, press the INITIALIZE key, first. This clears the flag without altering the current values for wavelength and temperature.

Third, keys A, B, and C are not used for data entry, but may be used for configuring the program for the type of calculation to be performed. For example, pressing D or E without first pressing A, B, or C will result in the calculation of the photon flux density in photons/cm²/s/ μ M or power density in W/cm²/ μ M, respectively. See the table showing sample test data and results. Pressing A first, for example, then pressing D or E will result, instead, in the calculation of the change in flux (either photons or power) per degree change in blackbody temperature. You may press pairs of prefix keys prior to calling for a calculation (e.g., A, C, E to find the change in power up to the cutoff per degree Kelvin). The prefix keys may be pressed in any sequence as long as you end up pressing D or E. NOTE: It doesn't make sense to use both B and C. The last one pressed takes precedence. If you have pressed any prefix keys and change your mind (or have made an error), pressing the INITIALIZE key will cancel and give you a fresh start. Stored values for wavelength and temperature are unaffected.

At the end of a calculation, the program displays in sequence (1) the key sequence which has been performed, (2) the temperature that was used, (3) the wavelength that was used, and (4) finally, the answer. The key sequence is displayed numerically proceeding from left to right, where the numbers represent the respective unshifted keys. Key A is 1, key B is 2; etc. For example, pressing C, A, D will display a key sequence of 314.000, where the number of trailing zeros depends upon the current display setting.

The following equations and procedures are used in BB (L = wavelength).

 $EQN4 = zc_1 (T/c_2)^{l-p} (l+p-1)!$

$$\begin{split} & EQN1 = c_1 (T/c_2)^{l-p} \, SUM \frac{inf}{n=1} \, \left[(l+p-1)!/n^2 \, EXP(-nc_2/LT) \, SUM \frac{l+p-1}{m=0} \, \left\{ (nc_2/LT)^m/m!) \right\} \right]. \\ & EQN2 = c_1/[L^{l+p+1} \, (EXP\{c_2/LT\}-1)]. \\ & EQN3 = c_1^2 \, EXP \, (c_2/LT) \, / \, [T^2 \, (EXP\{c_1/LT\}-1)]. \end{split}$$

Default conditions are: p = 0, $c_1 = hc^2/(2Pi) = 37415$, $c_2 = hc/k = 14388$, $zc_1 = 40495$ and use EQN2.

If prefix key A is used, then p=1; if using EQN2, then multiply by EQN3, and divide answer by c_2 .

If prefix key B is used, then use EQN4, instead.

If prefix key C is used, then use EQN1, instead.

If calculating power, then l = 4.

If calculating photon flux, then l = 3; use $c_1 = 1/k = 18837E19$, instead; if using EQN4, then use $zc_1 = 22642E19$, instead.

Using these equations and logical tests in this fashion permits calculation of many different parameters in a small program space.

PROGRAM LISTING FOR BB

01 /10 /100/	51 070 10		
81/10/1986	51 STO 12	184 *	157 RCL 96-
	52 RCL 12	105 RCL 13	158 RCL 13
GIALDI -DD-	53 RTN	196 Xt2	159 RCL 02
01+LBL -88- 02+LBL a	54+LBL II	197 *	160 YTX
03 37415	55 SF 99	108 RCL 10	161 /
84 STO 84	56+LBL E	109 /	162 RCL 01
	57 XEQ 07	119 GTO 01	163 1
95 14388	58 RCL 10	111+LBL 02	164 -
96 STO 19	59 RCL 11	112 1.202	165 FACT
07 18837 E19 08 STO 03	60 /	113 ENTERT	166 *
09 CLX	61 STO 13	114 1.9823	167 RCL 09
19+LBL 81	62 RCL 12	115 FS? 80	168 *
11 0	63 X≠8?	116 X<>Y	169 FS? 91
	64 /	117 STO 09	179 GTO 91
12 STO 15	65 STO 98	118 GTO 02	171 RCL 18
13 STO 14	66 4	119+LBL 03	172 /
14 STO 89	67 FS? 80	128 RCL 01	173 GTO 01
15 X<>Y 16 CF 90	68 3	121 STO 15	174+LBL e
17 SF 91	69 STO 85	122 0	175 .7896
18 CF 22	79 STO 01	123 RCL 08	176 /
19 SCI 3	71 STO 02	124 RCL 00	177+LBL d
20 RTN	72 1 77 CTO 00	125 *	178 3670
21+LBL b	73 STO 00	126 STO 97	179 /
22 FS?C 22	74 FS? 81	127+LBL 04	189 1/X
23 STO 11	75 GTO 14 76 ST+ 01	128 RCL 15	181 SCI 3
24 RCL 11	76 51+ 81 77 ST- 82	129 1	182 CF 22
25 RTN	78+LBL 14	130 -	183 END
26+LBL A	79 +	131 YfX	
27 CF 01	80 XEQ 05	132 LASTX	
28 XEQ 97	81 RCL 94	133 FACT	
29 1	82 FS? 99	134 /	
30 GTO 05	83 RCL 03	135 +	
31+LBL B	84 STO 86	136 RCL 97	
32 SF 02	85 GTO IND 15	137 DSE 15	
33+LBL C	86+LBL 09	138 GTO 64	
34 XEQ 87	87 RCL 12	139 EtX	
35 3	88 RCL 91	140 / 141 RCL 00	
36 FS?C 02	89 1		
37 2	98 +	142 RCL 05 143 YtX	
38 STO 15	91 YTX	144 /	
39+LBL 05	92 /	145 ST+ 09	
40 RCL 14	93 RCL 98	146 RCL 09	
41 10	94 EtX	147 /	
42 *	95 STO 09	148 FS? 00	
43 +	96 1	149 R-D	
44 STO 14	97 -	150 FIX 3	
45 FIX 0	98 /	151 RND	
46 RTN	99 FS? 01	152 ISG IND 15	
47+LBL 07	100 GTO 01	153 CLA	
48+L9L c	_ 101 LASTX	154 X#8?	
49 SCI 3	102 /	155 GTO 03	
50 FS?C 22	103 RCL 09	156+LBL 92	

5. SV. This program is a short, root-solving program which uses the secant method to iterate to a real solution of arbitrary, user-defined functions of the form: F(x) = 0. It is included here, since it is used as a subroutine by other programs in this write-all configuration. It may, also, be used for other applications as well.

The SV routine expects to find the name of the global label of the function to be solved in register 6 and an initial guess for X in register X (the display.) Do NOT use an initial guess of zero for X. Registers 6, 7, 8, and 9 are used by SV. XEQing SV will then result in an iterative, hopefully convergent, search for a value of X which makes the function identified in register 6 equal to zero. The successive values of X are displayed, so you can watch the search converge (or diverge). Termination of the search automatically occurs, when two successive values of X are equal within the resolution of the current display setting. This means that the accuracy of the answer may be determined by pre-selecting a display setting. Upon termination, the solution for X is in the X register (display) and in register 7. NOTE: When a program is running, the PRGM annunciator is visible in the display. When the program stops, the annunciator goes out.

For example, suppose we wish to find the solution to the equation:

$$X = 10 \wedge (-X).$$

This must be rewritten to take the form F(x) = 0, so:

$$0 = X - 10^{(-X)}$$
.

A program which performs this function and which starts with a global label must be written. Any two-letter, alphabetic label is global, so let's use the label "FN". (Assume X starts in the X register, and the answer is to be left in the X register.) The program would then look like:

LBL FN	The global label so SV can call it.
ENTER	Starting value in X; duplicate it in Y.
10 ^ X	Raise 10 to the X power.
1/X	Take the reciprocal (yields $10^{(-X)}$).
_	Subtract X from Y, leaving answer in X.
RTN	Return to calling routine.

Next, place the label of the function to be solved into register 6: ALPHA FN SHIFT STO 06 ALPHA.

Set the display to 5 significant figures: SHIFT FIX 5

Key in an initial guess: 1

Execute the SV routine: XEQ At PHA SV ALPHA

The routine will be observed to go through six iterations; finally, stopping at a solution for X of .39901. Executing FN with this value in the X register produces a result of 1 E-10 which is reasonably close to zero.

SV properly converges for routines in this WALL. However, for some user functions, it may have problems with bad initial guesses, or where multiple solutions exist (particularly, when some are imaginary), or when Xs near a root are invalid arguments (e.g., SQR(X) = 0 can't tolerate negative Xs.)

PROGRAM LISTING FOR SV

08 AUG 86

PRP "SV" 01+LBL "SV" 02 STO 07 03 XEQ IND 96 04 STO 08 05 RCL 07 06 1 07 % **08** STO 09 09 ST- 07 10+LBL 00 11 VIEW 07 12 RCL 07 13 XEQ IND 96 14 ENTERT 15 ST- Ø8 16 X<> 08 17 / 18 ST* 09 19 RCL 09 20 ST- 07 21 RCL 07 22 + 23 RND 24 RCL 07 25 RND 26 X≠Y? 27 GTO 00 28 RCL 07 29 RTN 30 .END.

6. GR-DIFF.

SHIFT A	SHIFT B	SHIFT C	SHIFT D	SHIFT E
ENTER	ENTER	ENTER	INTERCHANGE	TOGGLE
or	or	or	CONDITION	GR/DIFF
FIND	FIND	FIND	1 AND 2	
wavelength	detector temp	R or RoA		
for present condition	for present condition	for present condition		
A	_ B _	C ,	_ D _	Ε,

Below is a table showing six example pieces of data describing two different test conditions. Any five of these may be entered, and the program will solve for the sixth. The solution will assume either a diffusion limited detector or a G-R limited detector, depending on the status of the GR-DIFF toggle.

CONDITION	WAVELENGTH (μM)	TEMPERATURE (K)	R or RoA	
1	9	80	10	
2 (DIFF LTD.)	11.5	65	4.8	
2 (G-R LTD.)	11.5	65	6.9	

NOTE: If you can't remember the key definitions, press SHIFT RTN R/S.

The purpose of this program is to permit you to enter reported performance data for detectors which have the "wrong" cutoff or were tested at the "wrong" temperature and to extrapolate how the detectors would perform, if they had the "right" cutoff and/or were tested at the "right" temperature. Or, for example, you can take reported data and predict what temperature and/or wavelength of operation would be required to meet a desired R or RoA. One must assume a measure of quality of the detectors by specifying whether they are diffusion limited or G-R limited, this is done by pressing the GR/DIFF toggle. Current status is indicated prior to any result being displayed.

Only three keys (A, B, and C) are used to enter any of the six data. A is used for wavelength for both test conditions. B is used for temperature for both test conditions. C is used for R or RoA for both test conditions. Alternating between conditions is done with the D key. After any entry, the display will show the status of ALL THREE parameters for the current test condition. Read these values from left to right in the same order as keys A, B, and C. That is, wavelength, temperature, R or RoA. The parameters are separated by a? mark until a calculation is requested which makes all six data consistent.

For example, viewing the sample data at the beginning of par 6., suppose we were presented with test condition 1 and wanted to know what RoA to expect for a diffusion limited diode under test condition 2. If you're not sure whether the GR-DIFF toggle is set to the diffusion limited case, press the toggle once and see what condition occurs. If it's GR; then, press it again. NOTE: Performing a CLRG (SHIFT TAN) clears all registers and defaults to the diffusion limited case. Press 9, A, 80, B, 10, C, D (to

interchange which condition keys A, B, and C affect, and which condition is displayed), 11.5, A, 65, B, C (to solve for RoA for this condition). You may toggle between (and view) the two test conditions, at any time, by pressing D. You may toggle between diffusion limited and G-R limited operation, at any time, by pressing E. NOTE: If the calculation has been performed for one mode of operation (Say, G-R), and the other mode is selected,? marks are restored to the display to indicate inconsistent data.

The program may also be used when one of the test conditions is diffusion limited, and the other is G-R limited. But you have to get from here to there in two steps, and you must know (or assume) the temperature at which the break from diffusion limited to G-R limited operation occurs. For example, suppose a diode with a 4.2 μ M cutoff at 195 K has an Ro of 1E6 ohms. The break from diffusion limited to G-R limited operation for these diodes normally occurs near 130 K. You want to know what Ro to expect at 80 K. Strictly speaking, the cutoff will have changed when the diode is cooled to 80 K, but ignore that fact here. The procedure is as follows: CLRG (clears all registers and puts the machine into diffusion-limited regime, 4.2, A, 195, B, 1E6, C (test condition 1 now contains the 195 K performance), D, 4.2, A, 130, B, C (test condition 2 now contains the Ro at 130 K, diffusion limited, Ro = 6.5 E9), E (to toggle to G-R limited), D (test condition 1 will now represent the 80 K performance) (wavelength is still 4.2, so no need to reenter), 80, B, C (to find the G-R limited Ro at 80 K). The answer is Ro = 2.5 E13. More correct would be to use the correct predicted values for the wavelength at 130 K and 80 K, but solution for such parameters won't be covered until discussion of program HCT (par 7.).

PROGRAM EISTING FOR GR-DIFF

01/10/1986	F4 0
81, 10, 1700	51 +2+ 52 ccro +4
	52 ASTO 14
91+LBL *GR-BIFF*	53 STO 87
02 "a,T,RA,SHIFT,GD"	54 FS?C 22 55 GTO 01
03 PROMPT	56 XEQ 04
94+LBL D	57 XEQ 02
95 RCL 99	58 1438 8
96 X<> 19	59 RCL 13
97 STO 99	68 /
98 RCL 98	61 STO 86
09 X<> 11	62 RCL 09
10 STO 08	63 RCL 08
11 RCL 07	64 *
12 X() 12	65 /
13 STO 97	66 RCL 06
14+LBL 01	67 RCL 10
15 CLA	68 RCL 11
16 FIX 2	69 *
17 ARCL 99	79 /
18 ARCL 14	71 -
19 FIX 0	72 E†X
20 ARCL 98	73 RCL 12
21 ARCL 14	74 *
22 SCI 1	75 STO 97
23 ARCL 97	76 • •
24 PROMPT	77 ASTO 14
25+LBL 04	78 GTO 01
26 1	79+LBL B
27 RCL 13	80 *?*
28 X=Y?	81 ASTO 14
29 RTN	82 STO 88
38 2	83 FS?C 22
31 X=Y?	84 GTO 81
32 RTN	85 GTO 88
33+LBL E	86♦LBL A
34 *?*	87 •?•
35 ASTO 14	88 ASTO 14
36 RCL 13	89 STO 89
37 1	90 FS?C 22
38 X=Y?	91 GTO 01
39 2	92 SF 90
40 STO 13	93+LBL 00
41+LBL 92	94 XEQ 04
42 *DIFFUS,N*	95 XEQ 02
43 RCL 13	96 RCL 07
44 2	97 PCL 12
45 X=Y?	98 /
46 "G-R"	99 LH
47 "F LTD"	100 14338
48 AVIEN	101 /
49 RTN	192 RCL 13
50+LBL C	193 *

194 RCL 19 105 RCL 11 196 * 107 1/X 188 + 109 1/X 110 RCL 89 111 RCL 08 112 FS? 88 113 X<>Y 114 RDN 115 / 116 FS? 99 117 STO 09 118 FC?C 99 119 STO 08 129 - -121 ASTO 14 122 GTO 81 123 END

7. HCT, X, EG.

SHIFT A	SHIFT B	SHIFT C	SHIFT D	SHIFT E
cutoff (µM) ENTER temperature (K) FIND X composition	bandgap (eV) ENTER temperature (K) FIND X composition	X composition	temperature (K) FIND bandgap (eV)	temperature (K FIND cutoff (µM)
_ A	_ B _	c _	D _	Ε _

SAMPLE DATA AND RESULTS

	CALCULATI	ION TO FIND X		FOR A NEW	USE X TO	FIND:
CUTOFF	BANDGAP	TEMPERATURE	X	TEMPERATURE	BANDGAP	CUTOFF
4.2		195	.31879	80	.27342	4.543
	0.3	195	.32173	80	.27806	4.459

Registers used: 4 — Cutoff wavelength OR bandgap

5 — Temperature

6 - "X" alpha label for SV program

7 - X, either from direct entry or left by SV program

8 - Used by SV

9 - Used by SV

This program uses the empirical equation for bandgap in terms of temperature and X value developed by Hansen, Schmidt, and Casselman (HSC)¹, which is valid for a wide range of X:

$$Eg = -.302 + 1.93 X + (5.35E-4)T(1-2X) - 0.810 X^2 + 0.832 X^3.$$

It is generally desirable to determine the bandgap or cutoff that a device would have at some temperature from data which are available at some other temperature. The parameter which remains fixed in such calculations is the material composition, X. If X is known, it is stored into the program via label C; labels D and E calculate bandgap or cutoff directly from temperature. Sometimes, however, the data provided does not include X, so the HSC equation is solved iteratively for X as a function of T and (Eg or cutoff) through the use of labels A or B. The value found for X is displayed and saved by the program for use by D and E.

This program solves the HSC equation for X by calling the SV program, described elsewhere (par 5.), and searching for a root of the equation HSC - Eg = 0.

Global labels available from this program are HCT which behaves like local label A and may be used to find X from cutoff and temperature, and EG which calculates Eg from an internally stored value for T and an X in the X register. Of course, these may be called from other programs.

'Hansen, Schmidt, and Casselman (HSC), J. Appl. Phys. 53, 7099; 1982.

PROGRAM LISTING FOR HCT, X, EG

88 AUG 86

34 RTN 01+LBL "HCT" 35+LBL D 02+LBL A 36 STO 95 03 CF 00 37 RCL 07 94 GTO 91 38+LBL 00 05+L8L B 39+LBL "EG" 96 SF 99 40 ENTERT 07+LBL 01 98 FIX 9 41 ENTERT .09 -X-42 ENTERT 43 .832 10 ASTO 06 44 * 11 STO 05 45 .81 12 RDN 13 STO 04 46 -14 CLX 47 * 15 ENTERT 48 1.93 49 + 16 .25 17 SF 10 50 5.35 E-4 18 XEQ -SV-51 RCL 85 19 RTN 52 * 53 ENTERT 20+LBL E 21 XEQ D 54 RDN 55 ST+ X 22 1.242 23 / 56 -24 1/X 57 * **25 RTN** 58 + 26+LBL "X" 59 .302 27 XEQ 00 60 -28 FC? 98 61 RTN 29 1.242 62+LBL C 30 RCL 04 63 STO 07 31 FC? 00 64 END 32 / 33 -

8. NI, RØA.

	Na majority	CHOIC	CE	
lifetime (sec)	carrier concentration (/cc)	X (composition)	cutoff (µM)	detector temperature (K)
SHIFT A	SHIFT B	SHIFT C	SHIFT D	SHIFT E
				
base layer thickness (µM)	detector area (sq. cm.)	FIND saturation current (amps)	FIND RoA product (ohm*sq.cm.)	FIND intrinsic carrier concentration (/sq.cm.)
, А	В _	. c _	D	, E

Below is a table showing the data required, registers used, sample data, and results.

	TEST DATA	REGISTER USED
MINORITY CARRIER LIFETIME (s)	1E-7	1
MAJORITY CARRIER CONCENTRATION (/cm²)	5E15	2
COMPOSITION (X) OR	.21200	7
CUTOFF WAVELENGTH (μM)	12	4
DETECTOR TEMPERATURE (K)	80	5
BASE LAYER THICKNESS (µM)	10	3
DETECTOR AREA (cm²) (only req'd for Isat)	6.45E-6	12
	RESULTS FOR	CUTOFF = 12
INTRINSIC CARRIER CONCENTRATION (/cm²)	3.551E13	
PREDICTED RoA (ohm*cm²)	17.064	
SATURATION CURRENT (A)	2.606E-9	

This program uses the following equation to solve for RoA. It assumes that the device is diffusion limited, that the diffusion length is much longer than the base layer is thick, and that surface effects are not present. Also, lateral collection effects are not considered, unless one takes the A as the effective carrier collecting area and not the junction area.

$$RoA = \frac{k T Nat}{e^2 2 d Ni^2},$$

where e is the charge on an electron;

t is the minority carrier lifetime;

k is Boltzmann's constant;

T is the detector temperature;

d is the base layer thickness;

Na is the majority carrier concentration; and

Ni is the intrinsic carrier concentration.

All these parameters are user input, except the intrinsic carrier concentration which must be solved for from the detector temperature (already input), and the material composition (X). The equation used is from Hansen and Schmidt²:

$$Ni = [5.585 - 3.820 \text{ X} + (1.753\text{E}-3)\text{T} - (1.364\text{E}-3)\text{XT}] [(10^{14})\text{Eg}^{-25}\text{T}^{1.5}\text{e}^{-\text{Eg}/2\,k\,T}].$$

You have the option of providing the material cutoff wavelength instead of X, in which case, the program calls the HCT program to solve for X, and uses (1.24/cutoff) for Eg. If X is provided instead of the cutoff, the program calls the EG program to find Eg. NI keeps track of whether X or the cutoff has been input (and selected to predominate.) For example, if calculations are done for various device temperatures and X predominates, new values for Eg will be calculated at each temperature. If cutoff predominates, new values of X will be calculated at each temperature. If it is desired that the X value predominate, but only the cutoff is known, run the program once entering the known cutoff. Then, EITHER quickly jot down the X value that is briefly displayed and key it in via SHIFT C prior to any further calculations, OR merely clear flag 2.

The diode diffusion limited saturation current may be found, once the RoA is known, IF the diode area is known. The equation used is:

Isat =
$$\frac{k T}{e Ro}$$
, where $Ro = \frac{Ro A}{A}$.

As a point of interest, viewing the program code for LBL C (Isat), one observes that, despite the fact that ROA should be executed as a subroutine, the ROA routine is not run via an XEQ (which is a subroutine call) but via a GTO (which is a jump); and that ROA returns to the Isat routine based on the status of flag 3. The reason for this more-involved method for calling ROA lies in the fact that the HP41's RTN (return) stack is, only, six levels deep. This stack is where the HP41 keeps track of the location from which a subroutine has been called (the location where it must return at the end of a subroutine.) Following the program code, one finds that ROA calls NI, which may call label 01, which calls HCT, which calls SV, which calls X, which calls EG. If one tries to use ROA as a subroutine, the return address in the initial calling program gets pushed off the stack (and lost), when EG gets called; so the program terminates (incorrectly) in ROA.

²Hansen and Schmidt, J. Appl. Phys. 54, 3; March 1983.

PROGRAM LISTING FOR NI, RØA

01/10/1986	51+LBL 02 52 RCL 07 53 XEQ *EG*	103+LBL a
	52 RCL 07	184 STO 81
01+LBL -HI-		195 RTN
02+LBL E	54 1.24	106+LBL b
93 RCL 11	55 /	197 STO 92
84 FS? 01	56 1/X	108 RTN
85 RTN	57 FIX 2	1 89+ LBL c
96 FS? 92	58 *α=*	110 STO 97
07 XEQ 01	59 ARCL X	111 CF 01
98 FC? 92	60 AVIEN	112 CF 92
89 XEQ 82	61 STO 04	113 RTN
19 -1.364	62 RCL 97	114+LBL d
11 RCL 05	63 RTN	115 STO 04
12 *	64+LBL "ROA"	116 CF 91
13 3829	65+LBL D	117 SF 92
14 -	66 FIX 3	118 RTM
15 *	67 XEQ E	119 + LBL e
16 1.753	68 5378 E15	129 STO 95
17 RCL 05	69 X<>Y	121 CF 01
18 *	78 X12	122 RTH
19 +	71 /	123+LBL A
29 5585	72 RCL 05	124 STO 03
21 +	73 *	125 EHD
22 E11	74 RCL 92	
23 *	75 *	
24 1.24	76 RCL 93	
25 RCL 84	77 /	
26 /	78 RCL 01	
27 SQRT	79 *	
28 RCL 85	80 "RA="	
29 *	81 ARCL X	
38 SQRT	82 RYIEN	
31 3	83 FS?C 03	
32 YfX	84 GTO 03	
33 *	85 RTN	
34 7194 35 pg: 44	86+LBL 8	
35 RCL 84	87 STO 12	
36 /	88 RTN	
37 RCL 85	89+LBL C	
38 /	90 SF 03	
39 EtX	91 GTO D	
40 /	92+LBL 03	
41 SF 01	93 RCL 12	
42 STO 11	94 /	
43 CLD	95 RCL 05	
44 F[X 3	96 /	
45 RTN	97 116 05	
46+LBL 91	98 *	
47 RCL 84	99 1/X	
48 RCL 05	190 "[="	
49 XEQ "HCT"	191 ARCL X	
50 RTN	102 PROMPT	

SSSSFIESSSCOOL PROSPERING SSSSSSSSSFIESSSSSS

9. CONSTNT.

c speed of light	e _o permitivity of free space	sigma Stefan- Boltzmann constant	R gas constant	N _A Avogadro's number
SHIFT A	SHIFT B	SHIFT C	SHIFT D	SHIFT E
k Boltzmann constant	e charge on an electron	h Plank constant	h/(2*PI) Plank constant divided by (2*PI)	m _e mass of an electron
A .	_ B _	. c	D	_ Ε

This program may be used to conveniently bring any of the available physical constants into the X register for use in direct keyboard calculations. All constants are in MKS units. When any of the keys are pressed (SHIFT A through SHIFT E, or A through E) the current value in the X register is pushed up into the Y register, and the selected constant is placed in the X register. For example, suppose one wants to evaluate the following expression:

where wavelength = 4.2E-6 m, and T = 300 K.

The sequence that may be followed is:

PRESS	TO OBTAIN	SEE
SHIFT SCI 4	Floating point display and 5	significant figures
С	h	6.6262 -34
SHIFT A	c	2.9979 08
•.	Multiply X and Y registers	1.9865 -25
4.2 EEX CHS 6	Wavelength	4.2 -6
/	Divide Y register by X	4.7297 -20
A	k	1.3806 -23
/	Divide Y register by X	3.4258 03
300	T	300
/	Divide Y register by X	1.1419 01

PROGRAM LISTING FOR CONSTNT

81/18/1986

01+LBL -CONSTNT-924LBL a 03 2.997925 E8 04 RTN 95+LBL A 96 1.38962 E-23 87 RTN 98+LBL B 09 1.6022 E-19 10 RTN 11+LBL C 12 6.6262 E-34 13 RTN 14+LBL D 15 1.0546 E-34 16 RTN 17+LBL E 18 9.1096 E-31 19 RTN 20+LBL e 21 6.02217 E23 **22 RTN** 23+LBL b 24 8.85 E-12 **25 RTN** 26+LBL c 27 5.66961 E-8 **28 RTH** 29+LBL d 30 8.31434 31 RTN 32 END

10. INJEFF.

detector area (sq. cm.)	wavelength cuton (μΜ) ENTER cutoff (μΜ)	background temperature (K)	quantum efficiency (percent)	F/# (cold shield)
SHIFT A	SHIFT B	SHIFT C	SHIFT D	SHIFT E
zero bias resistance (ohms)	detector bias (volts)	detector temperature (K)	detector m value (1 = diff. ltd) ENTER CCD input derating factor	FIND Rd Q Ip Iv Rf
₽ A	В	С	(usually = 1.4)	IE E

Below is a table showing the data required, registers used, sample data, and results:

PARAMETER	REGISTER USED	SAMPLE DATA	RESULTS
DETECTOR AREA, A	16	1E-5	
CUTON	5	3.0	
CUTOFF	10	5.0	
BACKGROUND TEMPERATURE	12	300	
QUANTUM EFFICIENCY	17	80	
COLD SHIELD F/#	13	1	
ZERO BIAS RESISTANCE, Ro	9	1E6	
DETECTOR BIAS, V	2	02	
DETECTOR TEMPERATURE	14	200	
DETECTOR m VALUE (I = DIFF. LTD., 2 = G-R LTD	.) 3	1.2	
CCD DERATING FACTOR (m FOR CCD INPUT NO	DE) 11	1.4	
Rd = DIODE DYNAMIC RESISTANCE (OHMS)	l		2.63E6
Q = PHOTON FLUX (/cm2/s)	15		1.31E16
Ip = DIODE PHOTOCURRENT (A)		-	4.20E-9
Iv = DIODE BIAS CURRENT (A)			1.28E-8
Rf = CCD INPUT IMPEDANCE (OHMS)			1.42E6
(RECIPROCAL OF TRANSCONDUCTANCE)			
IE = INJECTION EFFICIENCY			0.650
		Other registers use	d: 4, 6, 7, 8

This program calculates injection efficiency from the equation:

$$IE = \frac{Rd}{(CCD \text{ derating factor})Rf + Rd}$$

Rf is the CCD input impedance and is the reciprocal of the term normally used: CCD input transconductance. Rf is computed from:

$$Rf = kT$$
, where Id is the net diode current = Iv + Ip.

Ip is the photocurrent induced in the photodiode by the background photon flux, Q, and is:

Iv is the diode current due to the fact that a bias is applied and is found from the equation of a diode:

$$Iv = \frac{mkT [EXP(-eV/\{mkT\})-1]}{e RO}.$$

Finally, Rd is the dynamic resistance of the diode at the specified bias. This may be found by differentiating the equation for Iv with respect to V and taking the reciprocal, so that:

$$Rd = Ro EXP(-eV/\{mkT\}).$$

When E is pressed to compute an injection efficiency, the intermediate results (Rd, Q, Ip, Iv, Rf), with identification, are flashed in the display, as they are found. The program stops with the injection efficiency displayed. If a printer is connected to the HP 41 and is on before the HP41 is turned on, all results will be printed. These data flash past too fast to be recorded without a printer and, if you're not interested in it, just ignore it. If your ARE interested in the intermediate results, set flag 21 using SHIFT SF 21 prior to pressing E. The HP 41 will stop at each intermediate value so that it may be recorded. Pressing R/S at each of these points will continue the program to the next result, ultimately displaying the value for the injection efficiency. You need set flag 21 only once, and it will remain set until you clear it using the FLAG routine, using SHIFT CF 21, or by turning the HP41 on with no printer connected.

PROGRAM LISTING FOR INJEFF

01/10/1986	51 "Rd="
	52 ARCL X
	53 AVIEN
01+LBL "INJEFF"	54 FS? 90
02+LBL a	55 GTO 90
93 STO 16	56 CF 02
94 RTN	57 RCL 10
05+LBL b	
96 STO 19	58 XEQ -Q88-
97 X()Y	59 STO 15
08 STO 05	60 RCL 05
99 CF 99	61 XEQ -QBB-
	62 ST- 15
10 RTH	63 SF 90
11+LBL c	64+LBL 99
12 STO 12	65 RCL 15
13 CF 00	66 "Q="
14 RTN	67 ARCL X
15+LBL d	68 AVIEN
16 STO 17	69 RCL 17
17 RTN	78 *
18+LBL e	71 RCL 13
19 STO 13	72 X†2
20 RTN	73 /
21+LBL A	74 4 E-22
22 STO 89	75 *
23 RTN	76 RCL 16
24+LBL B	77 *
25 STO 92	• * * * * * * * * * * * * * * * * * * *
26 RTN	78 CHS
27+LBL C	79 "IP="
28 STO 14	80 ARCL X
29 RTN	81 RYIEW
30+LBL D	82 RCL 04
. 34 CEO 11	83 1
31 STO 11	84 -
32 X()Y	85 RCL 06
33 STO 03	86 /
34 RTN	87 RCL 09
35+LBL E	88 /
36 SCI 2	89 RCL 03
37 11605	90 *
38 RCL 14	91 "[V="
39 /	92 ARCL X
40 STO 86	93 AVIEN
41 RCL 02	94 +
42 *	95 ABS
43 RCL 03	96 RCL 06
44 /	97 *
45 EfX	98 1/X
46 STO 94	99 RCL 11
47 1/X	100 +
48 RCL 09	101 "RF="
49 *	192 ARCL X
50 STO 01	103 HYIEN
	TOO HITCH

III. FINAL COMMENTS

As with any software, the results are only as valid as the data, the equations, and the program steps which are intended to represent them. The various programs have been tested and are believed to be correct and functional. However, if any errors are found, if any problems arise, or if you have and comments or questions, please let the author of this report know.

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